

# Switchmode Full Plastic Dual Schottky Barrier Power Rectifiers

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

#### **Features**

- \*Low Switching noise.
- \*High Current Capacity
- \* Guarantee Reverse Avalanche.
- \*Guard-Ring for Stress Protection.
- \*Low Power Loss & High efficiency.
- \*150°C Operating Junction Temperature
- \*Low Stored Charge Majority Carrier Conduction.
- \* Plastic Material used Carries Underwriters Laboratory
- \* Flammability Classification 94V-O
- \* Pb free
- \* In compliance with EU RoHs directives



## **MAXIMUM RATINGS**

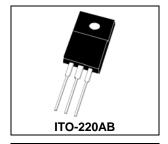
Characteristic	Symbol	SRF3045C	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	45	V
RMS Reverse Voltage	$V_{R(RMS)}$	32	V
Average Rectifier Forward Current Total Device (Rated V <sub>R</sub> ), T <sub>C</sub> =100°C	I <sub>F(AV)</sub>	15 30	А
Peak Repetitive Forward Current (Rate V <sub>R</sub> , Square Wave, 20kHz)	I <sub>FM</sub>	30	А
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-wave, single phase, 60Hz)	I <sub>FSM</sub>	250	А
Operating and Storage Junction Temperature Range	$T_J$ , $T_stg$	-65 to +150	$^{\circ}$ C

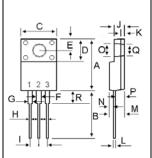
## **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Maximum Instantaneous Forward Voltage ( $I_F = 15 \text{ Amp } T_C = 25^{\circ}C$ ) ( $I_F = 15 \text{ Amp } T_C = 125^{\circ}C$ )	V <sub>F</sub>	1 1	0.53 0.47	0.55 	٧
Maximum Instantaneous Reverse Current ( Rated DC Voltage, $T_C = 25^{\circ}C$ ) ( Rated DC Voltage, $T_C = 125^{\circ}C$ )	I <sub>R</sub>		0.07 40	0.5 	mA

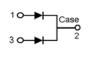
## SCHOTTKY BARRIER RECTIFIERS

30 AMPERES 45 VOLTS

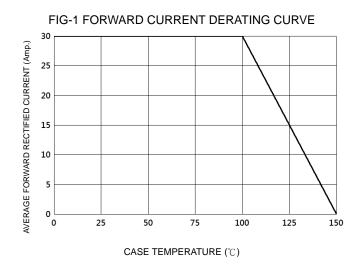


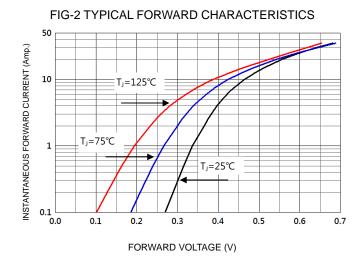


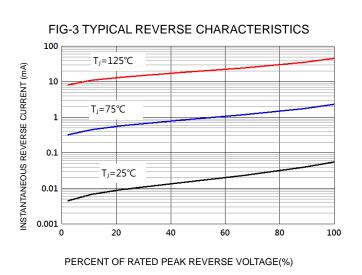
DIM	MILLIMETERS		
ווועו	MIN	MAX	
Α	14.80	16.10	
В	12.65	13.80	
С	9.85	10.36	
D	4.60	6.80	
E	2.50	3.50	
F	1.00	1.45	
G	1.00	1.45	
Н	0.30	0.90	
I	2.40	2.70	
J	2.34	3.30	
K	0.55	1.30	
L	0.36	0.80	
М	4.20	4.90	
N	1.10	1.80	
0	2.90	3.50	
Р	2.50	3.15	
Q	2.90	3.50	
R	3 10	4 85	

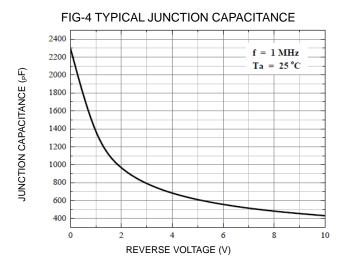


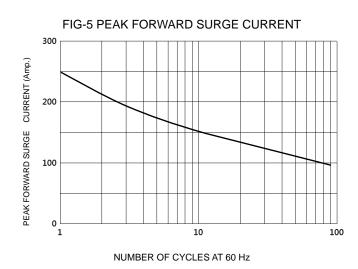














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